## NSN 5962-01-381-7528

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-381-7528

Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
B52hacmicg/fl e/i fscm 82918
Features Provided:
Programmed and tested to mil-std-883
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Input Circuit Pattern:
22 input
Case Outline Source And Designator:
D-9 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
4.5 volts applied and 5.5 volts applied
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Special Test Features:
Programmed and tested for the advanced cruise missile integration program for the center of gravity/fuel level advisory system
Terminal Type And Quantity:
24 printed circuit
Specification Data:
67268-5962-8605301la government standard and 82918-675-21117 manufacturers specification control
Departure From Cited Document:
Modified by programming
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0